85NT

ARLON ELECTRONIC MATERIALS

Polyimide Nonwoven Aramid

85NT is a pure polyimide laminate and prepreg system (Tg=250°C), reinforced with a non-woven aramid substrate. 85NT combines the high-reliability features of polyimide (improved PTH reliability and temperature stability) with the low in-plane (X,Y) expansion and outstanding dimensional stability of the aramid reinforcement.

Features:

- Low in-plane (X,Y) CTE of 7-9 ppm/°C allows attachment of SMT devices with minimal risk of solder joint due to CTE mismatch
- Nonwoven aramid reinforcement provides outstanding dimensional stability and enhanced registration for improved multilayer yields.
- Decomposition temperature of 426°C, compared with 407°C for pure polyimide, offering outstanding high-temperature processing stability
- Aramid reinforcement results in PCBs typically 25% lighter in weight than glass-reinforced laminates
- Laser and plasma ablatable for high speed formation of microvias and other features as small as 25µm (µ0.001”)
- Electrical and mechanical properties meeting the requirements of IPC-4101/53
- Compatible with lead-free processing

Typical Applications:

- Military and commercial avionics, missiles and missile defense, satellites, and other high-reliability SMT applications requiring low in-plane (X,Y) CTE values
- PCBs that are subjected to high temperatures during processing, such as lead-free soldering, HASL
- Applications with significant lifetimes with elevated temperature cycling, such as aircraft engine instrumentation, on-engine applications, or industrial sensors

85NT

Typical Properties:

Property	Units	Value	Test Method
Electrical Properties			
Dielectric Constant @ 1 MHz	-	3.6	IPC TM-650 2.5.5.3
@ 1 GHz	-		IPC TM-650 2.5.5.9
Dissipation Factor @ 1 MHz		0.014	IPC TM-650 2.5.5.3
@ 1 GHz			IPC TM-650 2.5.5.9
Volume Resistivity			
C96/35/90	MΩ-cm	2.0×10^8	IPC TM-650 2.5.17.1
E24/125	MΩ-cm	1.4×10^8	IPC TM-650 2.5.17.1
Surface Resistivity			
C96/35/90	MΩ	6.0×10^8	IPC TM-650 2.5.17.1
E24/125	MΩ	9.0×10^7	IPC TM-650 2.5.17.1
Electrical Strength	Volts/mil (kV/mm)	1000 (39.4)	IPC TM-650 2.5.6.2
Dielectric Breakdown	kV		IPC TM-650 2.5.6
Arc Resistance	sec	160	IPC TM-650 2.5.1
Thermal Properties			
Glass Transition Temperature (Tg)			
TMA	°C	250	IPC TM-650 2.4.24C
DSC	°C		IPC TM-650 2.4.25D
Decomposition Temperature			
Initial	°C	393	IPC TM-650 2.4.24.6
5% weight loss	°C	426	IPC TM-650 2.4.24.6
T260	min	>60	IPC TM-650 2.4.24.1
T288	min	>60	IPC TM-650 2.4.24.1
T300	min	>60	IPC TM-650 2.4.24.1
CTE (X,Y)	ppm/°C	7 - 9	IPC TM-650 2.4.41
CTE (Z)			
< Tg	ppm/°C	93	IPC TM-650 2.4.24C
> Tg	ppm/°C	279	IPC TM-650 2.4.24C
z-axis Expansion (50-260ºC)	%	2.3	IPC TM-650 2.4.24C
Mechanical Properties			
Peel Strength to Copper (1 oz/35 micron)			
After Thermal Stress	lb./in (N/mm)	4.3 (0.8)	IPC TM-650 2.4.8C
At Elevated Temperatures	lb./in (N/mm)	4.3 (0.8)	IPC TM-650 2.4.8.2A
After Process Solutions	lb./in (N/mm)	3.9 (0.7)	IPC TM-650 2.4.8C
Young's Modulus CD/MD	Mpsi (GPa)	1.95 (13.4)	ASTM E111
Flexural Strength	kpsi (MPa)	34 (234)	ASTM D3039
Tensile Strength CD/MD	kpsi (MPa)	28.6 (197)	ASTM D3039
Poisson's Ratio	-		ASTM E13204
Physical Properties			
Water Absorption (0.062")	%	0.6	IPC TM-650 2.6.2.1A
Density	g/cm^3	1.37	ASTM D792 Method A
Thermal Conductivity	W/mK	0.2	ASTM E1461
Flammability	class	N/A	UL-94

Results listed above are typical properties, provided without warranty, expressed or implied, and without liability. Properties may vary, depending on design and application. Arlon reserves the right to change or update these values.

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Availability:

Arlon Part Number	Glass Style	Resin (%)	Mil/Ply	Flow %
85NT147	E210	49	1.8	8
85NT247	E220	49	2.9	8
85NT347	E230	49	3.9	8
85NT153	E210	53	1.9	10
85NT253	E220	53	3.1	10
85NT353	E230	53	4.3	10

Recommended Process Conditions:

Process inner-layers through develop, etch, and strip using standard industry practices. Use brown oxide on inner layers. Adjust dwell time in the oxide bath to ensure uniform coating. Bake inner layers in a rack for 60 minutes at 107°C - 121°C (225°F - 250°F) immediately prior to lay-up. Vacuum desiccate the prepreg for 8 - 12 hours prior to lamination.

Lamination Cycle:

1) Pre-vacuum for 30 minutes

2) Control the heat rise to 4.5°C - 6.5°C (8°F - 12°F) per minute between 100°C and150°C (210°F and 300°F). Vacuum lamination is preferred. Start point vacuum lamination pressures are shownin the table below:

Panel Size		Pressure	
in.	mm	psi	kg/cm2
12 x 18	305 x 457	300	21
16 x 18	406 x 457	350	25
18 x 24	457 x 610	400	27

3) Set cure temperature at 218˚C (425˚F).

4) Cure time at temperature = 3.0 hours

5) Cool down under pressure at ≤ 6°C/min (10°F/min)

Drill at 350 - 400 SFM. Undercut bits are recommended for vias 0.023” (0.9cm) and smaller

De-smear using alkaline permanganate or plasma with settings appropriate for polyimide; plasma is preferred for positive etchback

Conventional plating processes are compatible with 85NT

Standard profiling parameters may be used; chip breaker style router bits are not recommended Bake for 1 - 2 hours at 250°F (121°C) prior to solder to reflow of HASL

* Refer to separate process guides for more details.

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